

## Description

### JMT N-channel MOSFET

#### Features

- $V_{DS}=20V$ ,  $I_D=4A$
- $R_{DS(ON)} < 27m\Omega$  @  $V_{GS} = 4.5V$
- $R_{DS(ON)} < 44 m\Omega$  @  $V_{GS} = 2.5V$
- High Power and Current Handling Capability
- Lead Free Product is Acquired
- Surface Mount Package

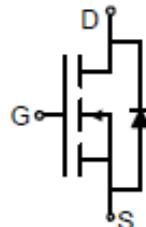
#### Application

- Battery Protection
- Load Switch
- Power Management

#### Package



SOT-23



#### Absolute Maximum Ratings ( $T_c=25^\circ C$ unless otherwise specified)

Symbol	Parameter		Max.	Units
$V_{DSS}$	Drain-Source Voltage		20	V
$V_{GSS}$	Gate-Source Voltage		$\pm 12$	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	4	A
		$T_c = 100^\circ C$	2.5	
$I_{DM}$	Pulsed Drain Current <sup>note1</sup>		10	A
$P_D$	Power Dissipation	$T_c = 25^\circ C$	1	W
$R_{eJA}$	Thermal Resistance, Junction to Ambient		125	$^\circ C/W$
$T_J$ , $T_{STG}$	Operating and Storage Temperature Range		-55 to +150	$^\circ C$

**Electrical Characteristics** ( $T_C=25^\circ\text{C}$  unless otherwise specified)

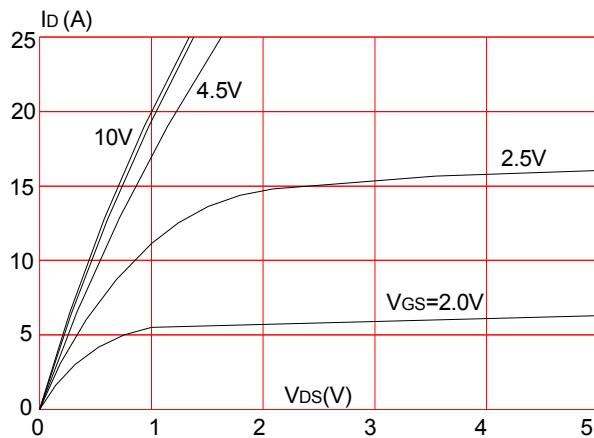
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristics</b>						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D = 250\mu\text{A}$	20	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 20V, V_{GS} = 0V,$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 12V$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.5	0.85	1.2	V
$R_{DS(\text{on})}$ note2	Static Drain-Source on-Resistance	$V_{GS} = 4.5V, I_D = 4A$	-	21	27	$\text{m}\Omega$
		$V_{GS} = 2.5V, I_D = 3A$	-	29	44	
$g_{FS}$	Forward Transconductance	$V_{DS} = 5V, I_D = 4A$	5	-	-	S
<b>Dynamic Characteristics</b>						
$C_{iss}$	Input Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$ $f = 1.0\text{MHz}$	-	300	-	pF
$C_{oss}$	Output Capacitance		-	120	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	80	-	pF
$Q_g$	Total Gate Charge	$V_{DS} = 10V, I_D = 4A,$ $V_{GS} = 4.5V$	-	4.0	-	nC
$Q_{gs}$	Gate-Source Charge		-	0.65	-	nC
$Q_{gd}$	Gate-Drain("Miller") Charge		-	1.2	-	nC
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-on Delay Time	$V_{DD} = 10V, I_D = 4A,$ $R_{GEN} = 6\Omega, V_{GS} = 4.5V,$	-	10	15	ns
$t_r$	Turn-on Rise Time		-	50	85	ns
$t_{d(off)}$	Turn-off Delay Time		-	17	45	ns
$t_f$	Turn-off Fall Time		-	10	20	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_s$	Maximum Continuous Drain to Source Diode Forward Current	-	-	4	A	
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	10	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0V, I_s = 2A$	-	0.75	1.2	V

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

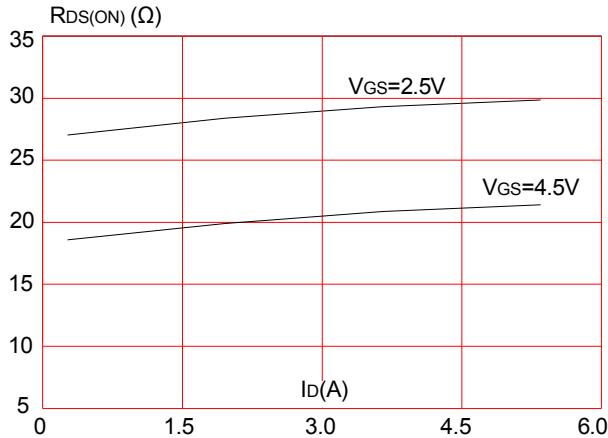
2. Pulse Test: Pulse Width $\leq 300\mu\text{s}$ , Duty Cycle $\leq 2\%$

## Typical Performance Characteristics

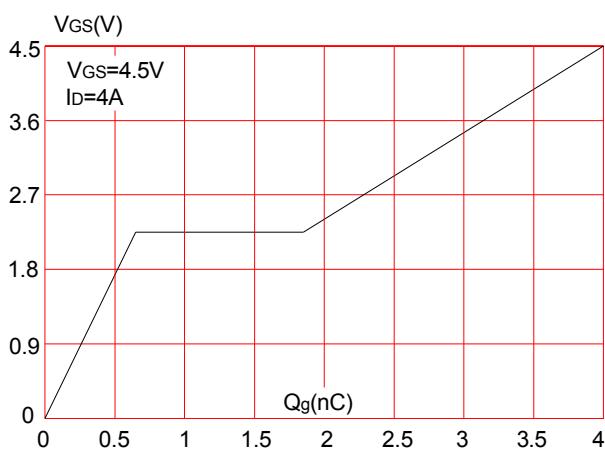
**Figure 1:** Output Characteristics



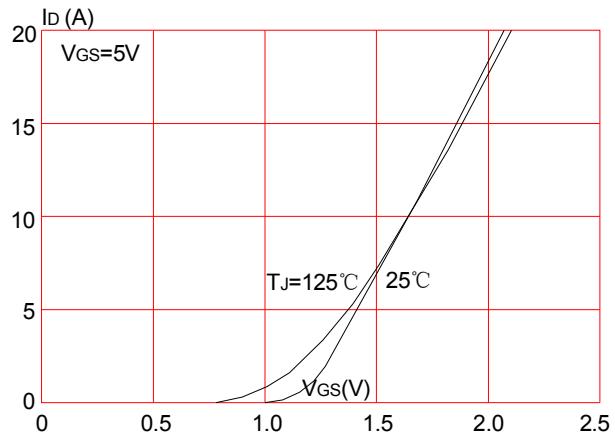
**Figure 3:** On-resistance vs. Drain Current



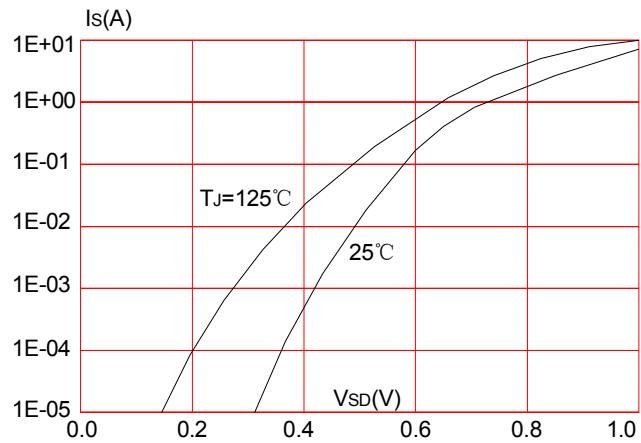
**Figure 5:** Gate Charge Characteristics



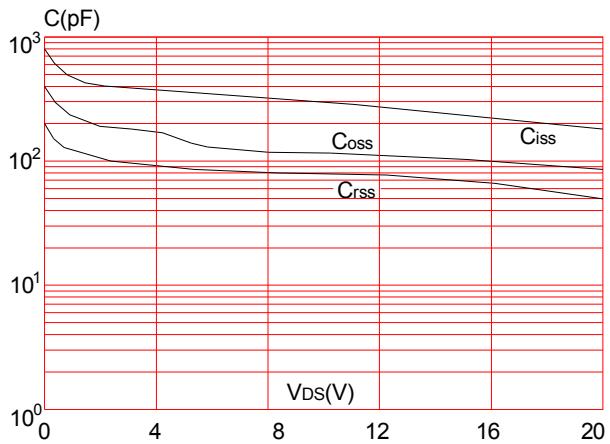
**Figure 2:** Typical Transfer Characteristics



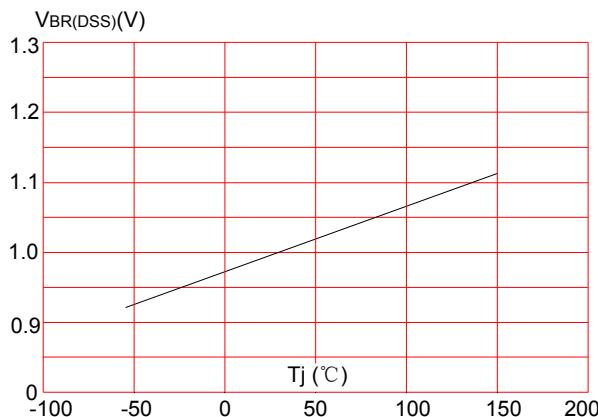
**Figure 4:** Body Diode Characteristics



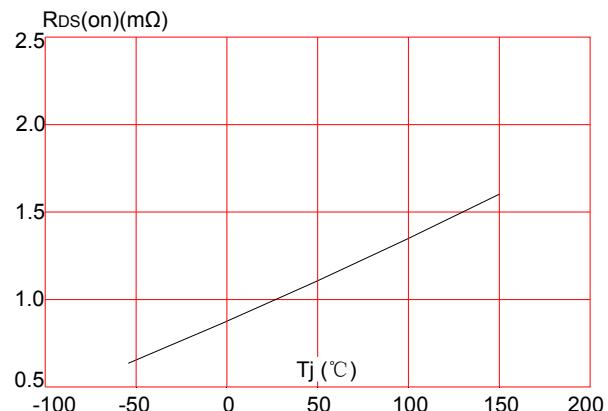
**Figure 6:** Capacitance Characteristics



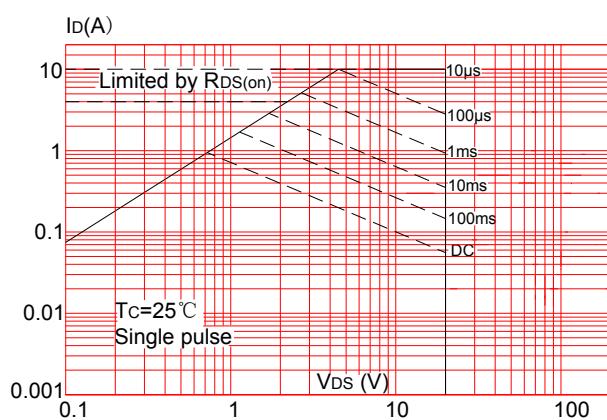
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



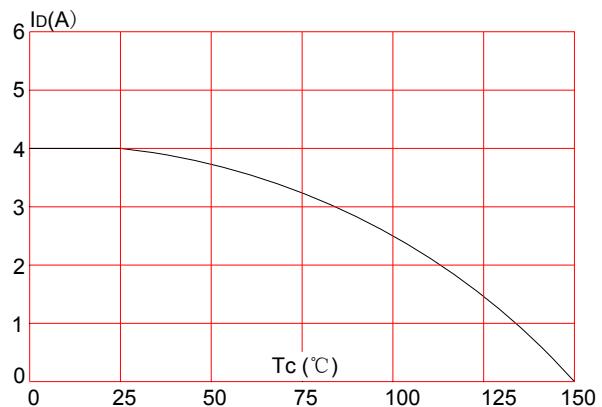
**Figure 8:** Normalized on Resistance vs. Junction Temperature



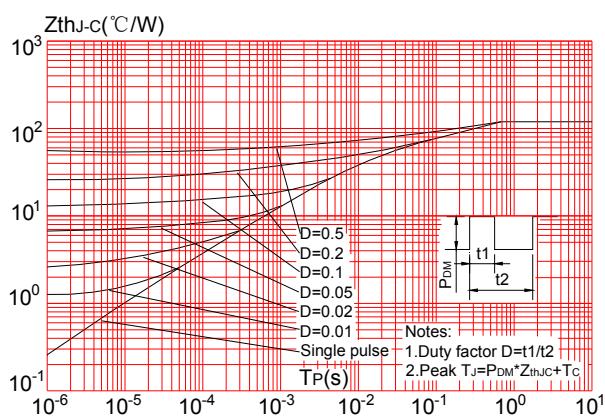
**Figure 9:** Maximum Safe Operating Area

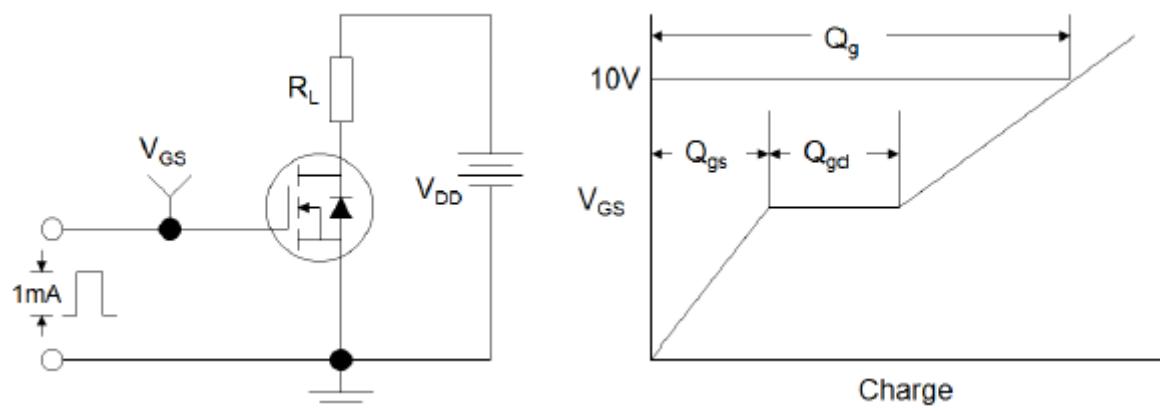


**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature

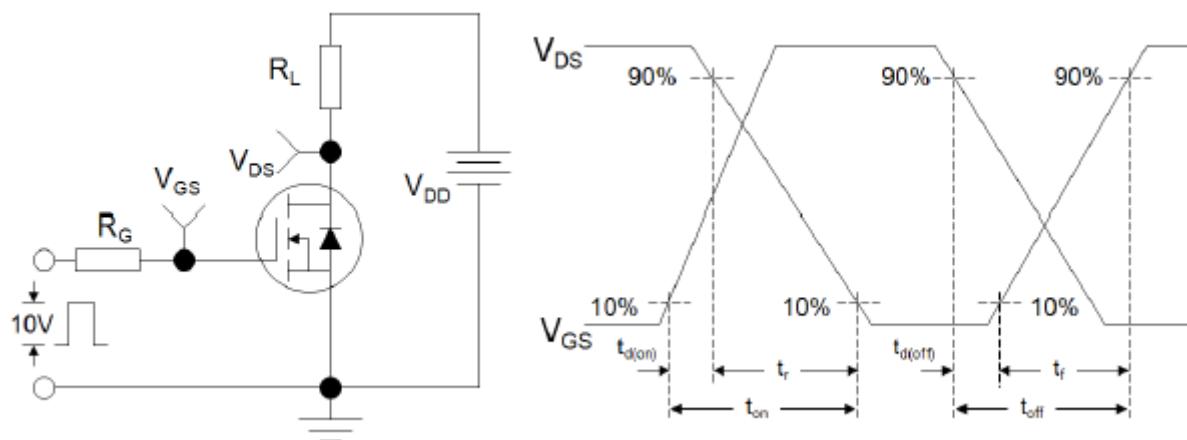


**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient (SOT-23)

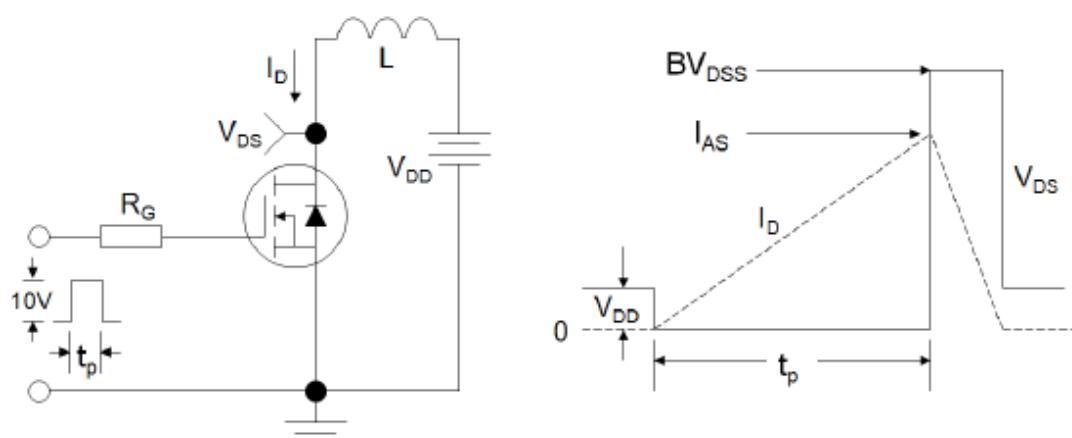




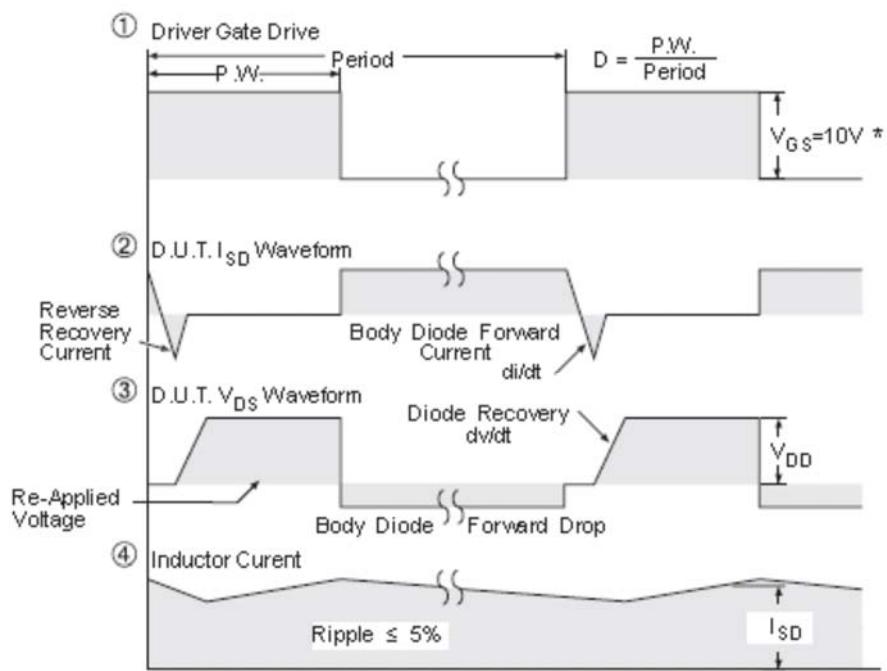
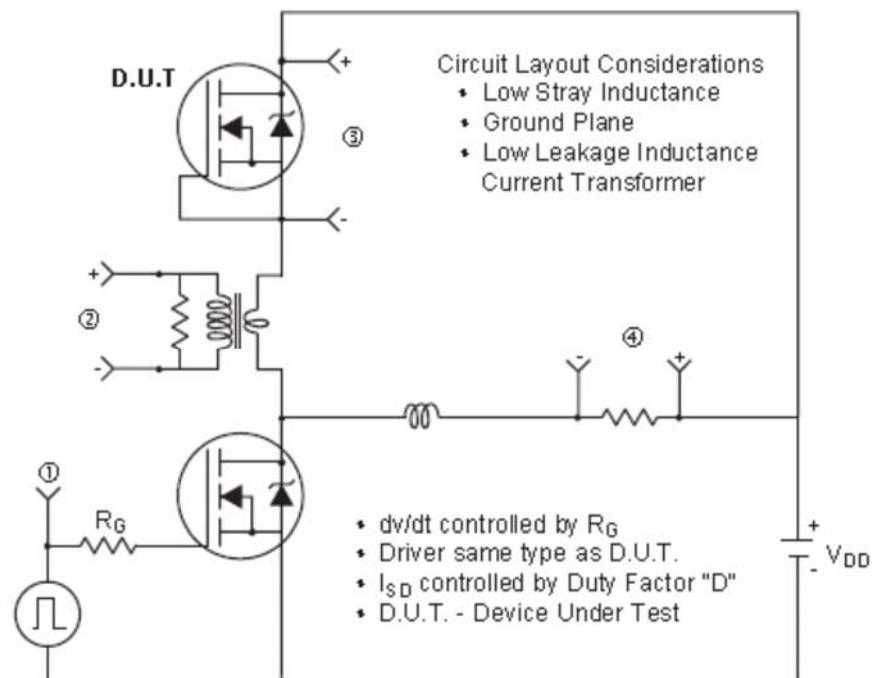
**Figure1:Gate Charge Test Circuit & Waveform**



**Figure 2: Resistive Switching Test Circuit & Waveforms**



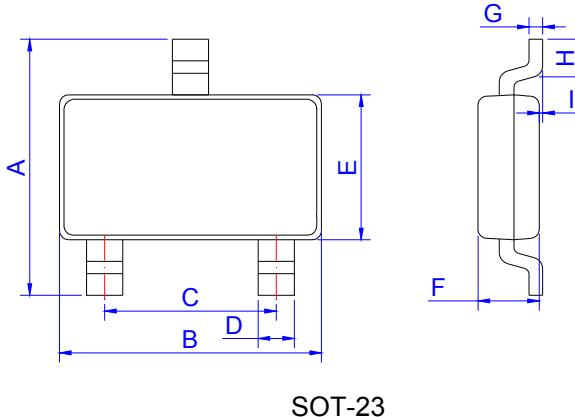
**Figure 3:Unclamped Inductive Switching Test Circuit & Waveforms**



\*  $V_{GS} = 5V$  for Logic Level Devices

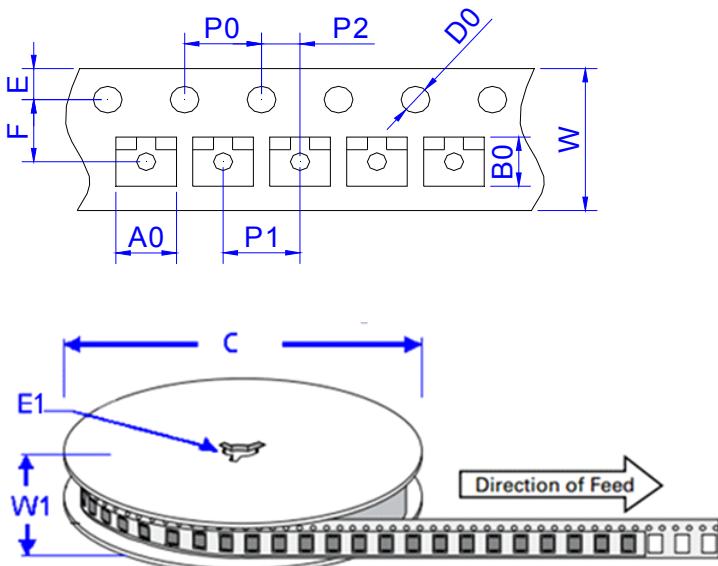
Figure 4:Peak Diode Recovery dv/dt Test Circuit & Waveforms (For N-channel)

## Package Mechanical Data



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.30	2.40	2.50	0.091	0.095	0.098
B	2.80	2.90	3.00	0.110	0.114	0.118
C	1.90 REF			0.075 REF		
D	0.35	0.40	0.45	0.014	0.016	0.018
E	1.20	1.30	1.40	0.047	0.051	0.055
F	0.90	1.00	1.10	0.035	0.039	0.043
G		0.10	0.15		0.004	0.006
H	0.20			0.008		
I	0		0.10	0		0.004

## Package Information-SOT-23



Ref.	Dimensions	
	Millimeters	Inches
A0	3.15 ± 0.3	0.124 ± 0.012
B0	2.77 ± 0.3	0.109 ± 0.012
C	178	7.0
D0	1.50 ± 0.1	0.059 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	3.5 ± 0.2	0.138 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	8.00 ± 0.2	0.315 ± 0.008
W1	11.5 ± 1.0	0.453 ± 0.039

## Ordering Information-SOT-23

OUTLINE	PACKAGE TYPE	QUANTITY REEL	DESCRIPTION
TAPING	SOT-23	3,000pcs	7 inch reel pack